



**2SC2383**

**NPN EPITAXIAL SILICON TRANSISTOR**

**COLOR TV AUDIO OUTPUT & COLOR TV VERTICAL OUTPUT**

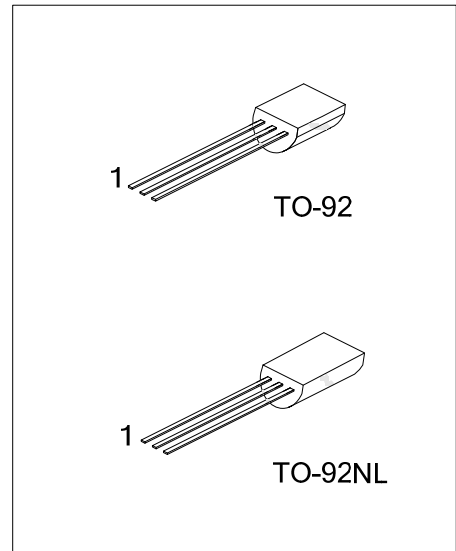
■ DESCRIPTION

The UTC **2SC2383** is an NPN epitaxial silicon transistor, it uses UTC's advanced technology to provide customers high DC current gain and high breakdown voltage.

The UTC **2SC2383** is usually used in Color TV Vertical Deflection Output and Audio Output.

■ FEATURES

- \* High breakdown Voltage
- \* High DC Current Gain



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SC2383L-x-T92-B	2SC2383G-x-T92-B	TO-92	E	C	B	Tape Box
2SC2383L-x-T92-K	2SC2383G-x-T92-K	TO-92	E	C	B	Bulk
2SC2383L-x-T9N-B	2SC2383G-x-T9N-B	TO-92NL	E	C	B	Tape Box
2SC2383L-x-T9N-K	2SC2383G-x-T9N-K	TO-92NL	E	C	B	Bulk

Note: Pin Assignment: C: Collector B: Base E: Emitter

<p>2SC2383G-x-T92-B</p> <p>(1) Packing Type (2) Package Type (3) Rank (4) Green Package</p>	<p>(1) B: Tape Box, K: Bulk (2) T92: TO-92, T9N: TO-92NL (3) x: refer to Classification of <math>h_{FE}</math> (4) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ MARKING

TO-92	TO-92NL

■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ , unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	160	V
Collector-Emitter Voltage	$V_{CEO}$	160	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current	$I_C$	1	A
Base Current	$I_B$	0.5	A
Collector Power Dissipation	$P_C$	900	mW
Junction Temperature	$T_J$	+150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-55 ~ 150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ , unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current	$I_{CBO}$	$V_{CE}=150\text{V}, I_E=0$			1	$\mu\text{A}$
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB}=6\text{V}, I_C=0$			1	$\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	$I_C=10\text{mA}, I_B=0$	160			V
DC Current Gain	$h_{FE}$	$V_{CE}=5\text{V}, I_C=200\text{mA}$	60		320	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$			1.5	V
Base-Emitter On Voltage	$V_{BE(on)}$	$V_{CE}=5\text{V}, I_C=5\text{mA}$	0.45		0.75	V
Current Gain Bandwidth Product	$f_T$	$V_{CE}=5\text{V}, I_C=200\text{mA}$	20	100		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			20	pF

■  $h_{FE}$  CLASSIFICATION

CLASSIFICATION	R	O	Y
$h_{FE}$	60 ~ 120	100 ~ 200	160 ~ 320

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